# NSN 5962-01-179-3618

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# Body Length: 1.290 inches Body Width: Between 0.500 inches and 0.610 inches Body Height:

0.210 inches

#### **Maximum Power Dissipation Rating:**

1.8 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+125.0 degrees celsius

#### **End Application:**

126001|110148

#### Features Provided:

Hermetically sealed and burn in and erasable and programmable and positive outputs

#### Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

#### Output Logic Form:

Transistor-transistor logic

#### Input Circuit Pattern:

21 input

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

6.0 volts power source

#### **Time Rating Per Chacteristic:**

300.00 nanoseconds propagation delay time, low to high level output and 300.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

### **Test Data Document:**

07187-8001760 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

24 printed circuit

# Shelf Life:

N/a

### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

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